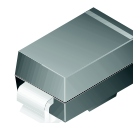


General Purpose Rectifiers (Glass Passivated)

GF1A, GF1B, GF1D, GF1G, GF1J, GF1K, GF1M

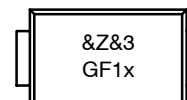
Features

- Low Forward Voltage Drop
- High Current Capability
- Easy Pick and Place
- High Surge Current Capability
- These Devices are Pb-Free, Halide Free and are RoHS Compliant



COLOR BAND DENOTES CATHODE
SMA (DO-214AC)
CASE 403AE

MARKING DIAGRAM



&Z = Assembly Plant Code
 &3 = 3-Digit Date Code
 GF1x = Specific Device Code
 (x = A, B, D, G, J, K, M)

ORDERING INFORMATION

Device	Package	Shipping [†]
GF1A	SMA (Pb-Free, Halide Free)	7500 / Tape & Reel
GF1B		
GF1D		
GF1G		
GF1J		
GF1K		
GF1M		

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, [BRD8011/D](#).

GF1A, GF1B, GF1D, GF1G, GF1J, GF1K, GF1M

ABSOLUTE MAXIMUM RATINGS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Value							Unit
		1A	1B	1D	1G	1J	1K	1M	
V _{RRM}	Maximum Repetitive Reverse Voltage	50	100	200	400	600	800	1000	V
I _{F(AV)}	Average Rectified Forward Current, @ T _L = 125°C	1.0							A
I _{FSM}	Non-repetitive Peak Forward Surge Current 8.3 ms Single Half-Sine-Wave	30							A
T _{stg}	Storage Temperature Range	-65 to +175							°C
T _J	Operating Junction Temperature	-65 to +175							°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

Symbol	Parameter	Value	Unit
P _D	Power Dissipation	1.8	W
R _{θJA}	Thermal Resistance, Junction to Ambient*	80	°C/W
R _{θJL}	Thermal Resistance, Junction to Lead*	26	°C/W

*Device mounted on PCB with 0.2 x 0.2" (5.0 x 5.0 mm) copper pad areas.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

Symbol	Parameter	Device							Unit
		1A	1B	1D	1G	1J	1K	1M	
V _F	Forward Voltage @ 1.0 A	1.0					1.2		V
t _{rr}	Reverse Recovery Time I _F = 0.5 A, I _R = 1.0 A, I _{rr} = 0.25 A	2.0							μs
I _R	Reverse Current @ Rated V _R T _A = 25°C T _A = 125°C	5.0 50.0							μA μA
C _T	Total Capacitance V _R = 4.0 V, f = 1.0 MHz	15							pF

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

GF1A, GF1B, GF1D, GF1G, GF1J, GF1K, GF1M

TYPICAL CHARACTERISTICS

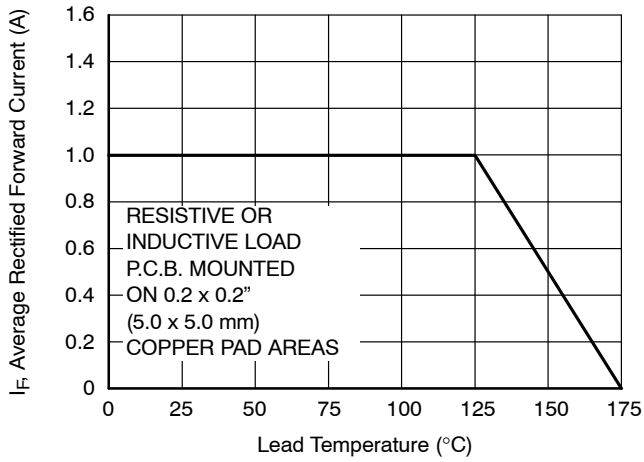


Figure 2. Forward Current Derating Curve

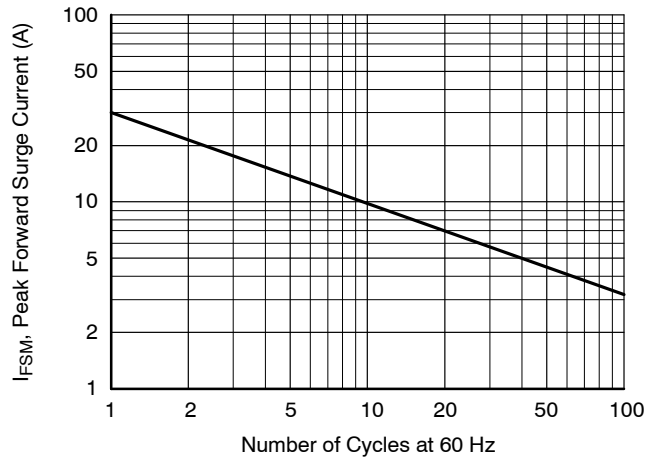


Figure 3. Non-Repetitive Surge Current

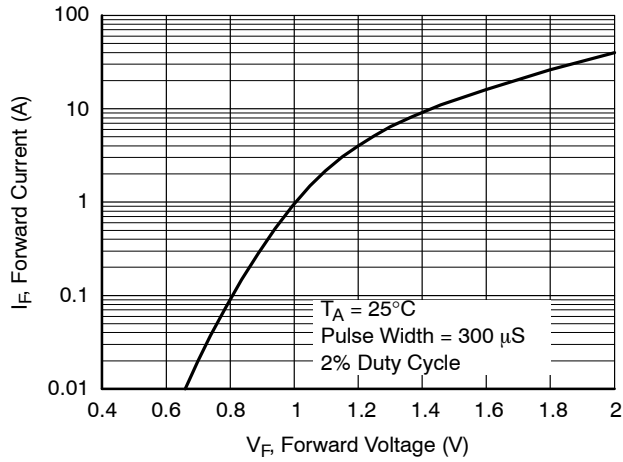


Figure 1. Forward Voltage Characteristics

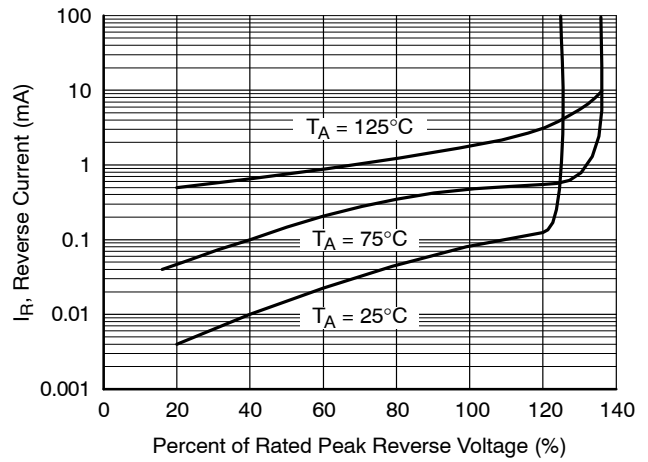


Figure 4. Reverse Current vs. Reverse Voltage

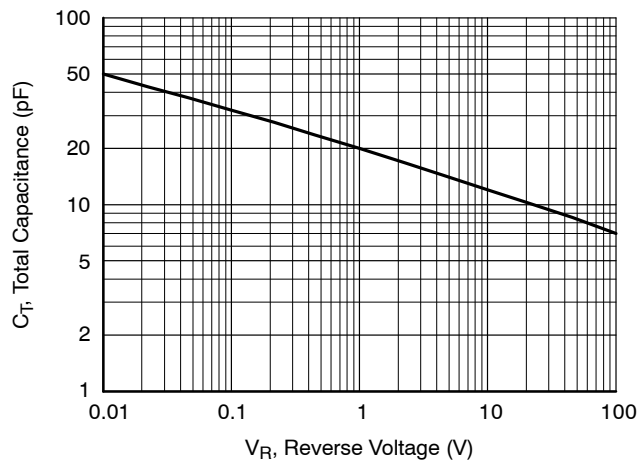
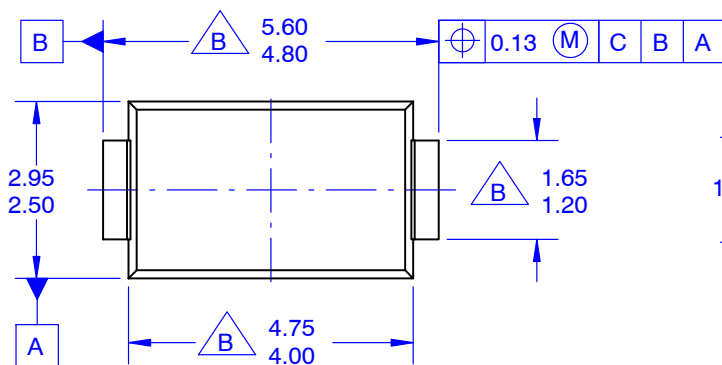


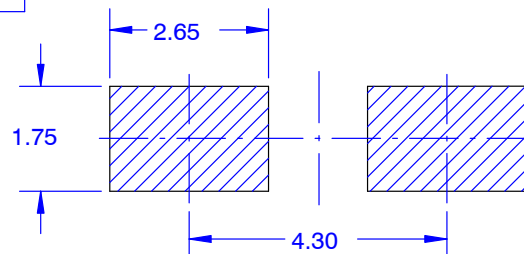
Figure 5. Total Capacitance

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ISSUE O

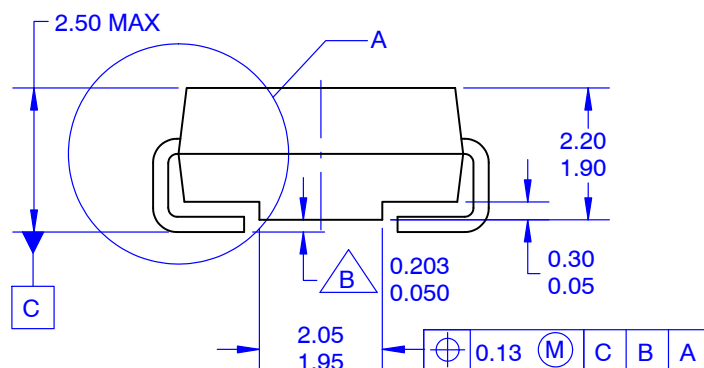
DATE 31 AUG 2016



TOP VIEW



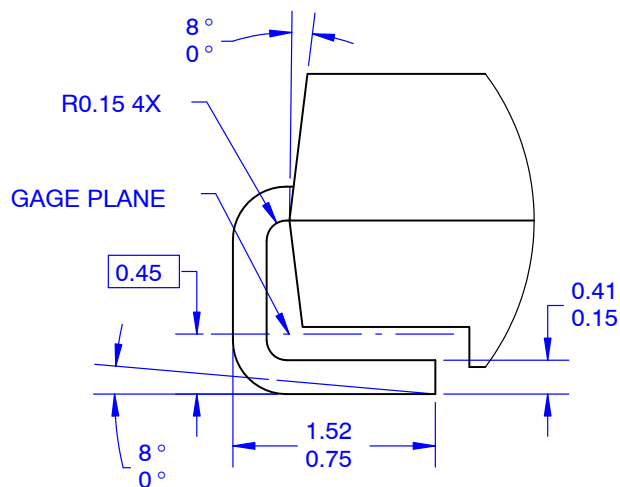
LAND PATTERN RECOMMENDATION



SIDE VIEW

NOTES:

- A. EXCEPT WHERE NOTED, CONFORMS TO JEDEC DO214 VARIATION AC.
-  B. DOES NOT COMPLY JEDEC STANDARD VALUE.
- C. ALL DIMENSIONS ARE IN MILLIMETERS.
- D. DIMENSIONS ARE EXCLUSIVE OF BURRS, MOLD FLASH AND TIE BAR PROTRUSIONS.
- E. DIMENSIONS AND TOLERANCE AS PER ASME Y14.5-2009.
- F. LAND PATTERN STD. DIOM5025X231M



DETAIL A
SCALE 20 : 1

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